

# Programmable Shunt Regulator



## LM431SA, LM431SB, LM431SC

### Description

The LM431SA / LM431SB / LM431SC are three-terminal the output adjustable regulators with thermal stability over operating temperature range. The output voltage can be set any value between  $V_{REF}$  (approximately 2.5 V) and 36 V with two external resistors. These devices have a typical dynamic output impedance of 0.2  $\Omega$ . Active output circuit provides a sharp turn-on characteristic, making these devices excellent replacement for zener diodes in many applications.

### Features

- Programmable Output Voltage to 36 V
- Low Dynamic Output Impedance: 0.2  $\Omega$  (Typical)
- Sink Current Capability: 1.0 to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/ $^{\circ}$ C (Typical)
- Temperature Compensated for Operation Over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- Fast Turn-on Response
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

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1  
SOT-89  
CASE 528AH

1. Ref
2. Anode
3. Cathode



3  
SOT-23FL  
CASE 318AB

1. Cathode
2. Ref
3. Anode



3  
SOT-23  
CASE 318BM

- |            |            |
|------------|------------|
| M32        | M3         |
| 1. Ref     | 1. Cathode |
| 2. Cathode | 2. Ref     |
| 3. Anode   | 3. Anode   |

### ORDERING INFORMATION

Product Number	Output Voltage Tolerance	Operating Temperature	Top Mark <sup>(1)</sup>	Package	Shipping <sup>†</sup>
LM431SACMFX	2%	-25 to +85 $^{\circ}$ C	43A □	SOT-23FL 3L	Tape and Reel
LM431SACM3X			43L ⊙	SOT-23 3L	
LM431SACM32X			43G ⊙	SOT-23 3L	
LM431SBCMLX	1%		43B	SOT-89 3L	
LM431SBCMFX			43B □	SOT-23FL 3L	
LM431SBCM3X			43M ⊙	SOT-23 3L	
LM431SBCM32X			43H ⊙	SOT-23 3L	
LM431SCCMLX	0.5%		43C	SOT-89 3L	
LM431SCCMFX			43C □	SOT-23FL 3L	
LM431SCCM3X			43N ⊙	SOT-23 3L	
LM431SCCM32X			43J ⊙	SOT-23 3L	
LM431SAIMFX	2%		-40 to +85 $^{\circ}$ C	43AI	
LM431SBIMFX	1%	43BI		SOT-23FL 3L	
LM431SCIMFX	0.5%	43CI		SOT-23FL 3L	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. SOT-23 and SOT-23FL have basically four-character marking except LM431SAIMFX. (3 letters for device code + 1 letter for date code) SOT-23FL date code is composed of 1 digit numeric or alphabetic week code adding bar-type year code.

# LM431SA, LM431SB, LM431SC

## Block Diagram

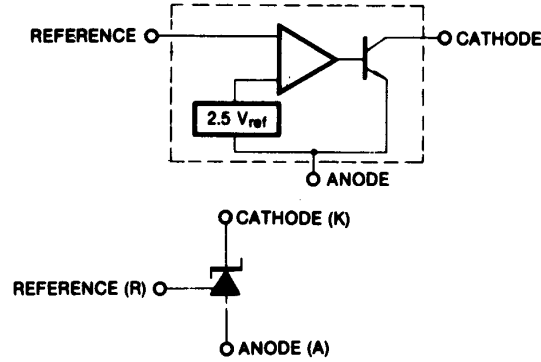


Figure 1. Block Diagram

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter		Value	Unit
V <sub>KA</sub>	Cathode Voltage		37	V
I <sub>KA</sub>	Cathode current Range (Continuous)		-100 to +150	mA
I <sub>REF</sub>	Reference Input Current Range		-0.05 to +10.00	mA
R <sub>θJA</sub>	Thermal Resistance Junction–Air (2, 3)	ML Suffix Package (SOT–89)	220	°C/W
		MF Suffix Package (SOT–23FL)	350	
		M32, M3 Suffix Package (SOT–23)	400	
P <sub>D</sub>	Power Dissipation (4, 5)	ML Suffix Package (SOT–89)	560	mW
		MF Suffix Package (SOT–23FL)	350	
		M32, M3 Suffix Package (SOT–23)	310	
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>OPR</sub>	Operating Temperature Range	All products except LM431SAIMFX	-25 to +85	°C
		LM431SAIMFX, SBIMFX, SCIMFX	-40 to +85	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Thermal resistance test board  
Size: 1.6 mm x 76.2 mm x 114.3 mm (1S0P) JEDEC Standard: JESD51–3, JESD51–7.
- Assume no ambient airflow.
- T<sub>JMAX</sub> = 150°C; ratings apply to ambient temperature at 25°C.
- Power dissipation calculation: P<sub>D</sub> = (T<sub>J</sub> – T<sub>A</sub>) / R<sub>θJA</sub>.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V <sub>KA</sub>	Cathode Voltage	V <sub>REF</sub>	36	V
I <sub>KA</sub>	Cathode Current	1	100	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# LM431SA, LM431SB, LM431SC

**ELECTRICAL CHARACTERISTICS** (Note 6, Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Conditions	LM431SA			LM431SB			LM431SC			Unit	
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
$V_{REF}$	Reference Input Voltage	$V_{KA} = V_{REF}, I_{KA} = 10 \text{ mA}$	2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V	
$\Delta V_{REF} / \Delta T$	Deviation of Reference Input Voltage Over Temperature	$V_{KA} = V_{REF}, I_{KA} = 10 \text{ mA}, T_{MIN} \leq T_A \leq T_{MAX}$	SOT-89 SOT-23FL		4.5	17.0		4.5	17.0		4.5	17.0	mV
			SOT-23		6.6	24		6.6	24		6.6	24	mV
$\frac{\Delta V_{REF}}{\Delta V_{KA}}$	Ratio of Change in Reference Input Voltage to the Change in Cathode Voltage	$I_{KA} = 10 \text{ mA}$	$\Delta V_{KA} = 10 \text{ V} - V_{REF}$		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	mV/V
			$\Delta V_{KA} = 36 \text{ V} - 10 \text{ V}$		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	
$I_{REF}$	Reference Input Current	$I_{KA} = 10 \text{ mA}, R_1 = 10 \text{ K}\Omega, R_2 = \infty$		1.5	4.0		1.5	4.0		1.5	4.0	$\mu\text{A}$	
$\Delta I_{REF} / \Delta T$	Deviation of Reference Input Current Over Full Temperature Range	$I_{KA} = 10 \text{ mA}, R_1 = 10 \text{ K}\Omega, R_2 = \infty, T_A = \text{Full Range}$	SOT-89 SOT-23FL		0.4	1.2		0.4	1.2		0.4	1.2	$\mu\text{A}$
			SOT-23		0.8	2.0		0.8	2.0		0.8	2.0	$\mu\text{A}$
$I_{KA(MIN)}$	Minimum Cathode Current for Regulation	$V_{KA} = V_{REF}$		0.45	1.00		0.45	1.00		0.45	1.00	mA	
$I_{KA(OFF)}$	Off -Stage Cathode Current	$V_{KA} = 36 \text{ V}, V_{REF} = 0$		0.05	1.00		0.05	1.00		0.05	1.00	$\mu\text{A}$	
$Z_{KA}$	Dynamic Impedance	$V_{KA} = V_{REF}, I_{KA} = 1 \text{ to } 100 \text{ mA}, f \geq 1.0 \text{ kHz}$		0.15	0.50		0.15	0.50		0.15	0.50	$\Omega$	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. LM431SAI, LM431SBI, LM431SCI: -  $T_{A(min)} = -40^\circ\text{C}$ ,  $T_{A(max)} = +85^\circ\text{C}$

All other pins: -  $T_{A(min)} = -25^\circ\text{C}$ ,  $T_{A(max)} = +85^\circ\text{C}$

# LM431SA, LM431SB, LM431SC

## ELECTRICAL CHARACTERISTICS (Continued) (Notes 7 and 8, Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted)

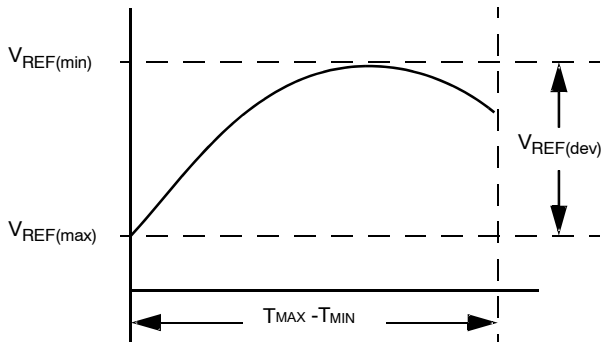
Symbol	Parameter	Conditions	LM431SAI			LM431SBI			LM431SCI			Unit	
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
$V_{REF}$	Reference Input Voltage	$V_{KA} = V_{REF}$ , $I_{KA} = 10\text{ mA}$	2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V	
$V_{REF(dev)}$	Deviation of Reference Input Voltage Over-Temperature	$V_{KA} = V_{REF}$ , $I_{KA} = 10\text{ mA}$ , $T_{MIN} \leq T_A \leq T_{MAX}$		5	20		5	20		5	20	mV	
$\frac{\Delta V_{REF}}{\Delta V_{KA}}$	Ratio of Change in Reference Input Voltage to Change in Cathode Voltage	$I_{KA} = 10\text{ mA}$	$\Delta V_{KA} = 10\text{ V} - V_{REF}$		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	mV/V
			$\Delta V_{KA} = 36\text{ V} - 10\text{ V}$		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	
$I_{REF}$	Reference Input Current	$I_{KA} = 10\text{ mA}$ , $R_1 = 10\text{ K}\Omega$ , $R_2 = \infty$		1.5	4.0		1.5	4.0		1.5	4.0	$\mu\text{A}$	
$I_{REF(dev)}$	Deviation of Reference Input Current Over Full Temperature Range	$I_{KA} = 10\text{ mA}$ , $R_1 = 10\text{ K}\Omega$ , $R_2 = \infty$ , $T_{MIN} \leq T_A \leq T_{MAX}$		0.8	2.0		0.8	2.0		0.8	2.0	$\mu\text{A}$	
$I_{KA(MIN)}$	Minimum Cathode Current for Regulation	$V_{KA} = V_{REF}$		0.45	1.00		0.45	1.00		0.45	1.00	mA	
$I_{KA(OFF)}$	Off-Stage Cathode Current	$V_{KA} = 36\text{ V}$ , $V_{REF} = 0$		0.05	1.00		0.05	1.00		0.05	1.00	$\mu\text{A}$	
ZKA	Dynamic Impedance	$V_{KA} = V_{REF}$ , $I_{KA} = 1\text{ to }100\text{ mA}$ , $f \geq 1.0\text{ kHz}$		0.15	0.50		0.15	0.50		0.15	0.50	$\Omega$	

7. LM431SAI, LM431SBI, LM431SCI:  $-T_{A(min)} = -40^\circ\text{C}$ ,  $T_{A(max)} = +85^\circ\text{C}$

All other pins:  $-T_{A(min)} = -25^\circ\text{C}$ ,  $T_{A(max)} = +85^\circ\text{C}$

8. The deviation parameters  $V_{REF(dev)}$  and  $I_{REF(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage,  $\alpha V_{REF}$ , is defined as:

$$|\alpha V_{REF}| \left( \frac{\text{ppm}}{^\circ\text{C}} \right) = \frac{\left( \frac{V_{REF(dev)}}{V_{REF(at\ 25^\circ\text{C})}} \right) \cdot 10^6}{T_{MAX} - T_{MIN}}$$



where  $T_{MAX} - T_{MIN}$  is the rated operating free-air temperature range of the device.

$\alpha V_{REF}$  can be positive or negative, depending on whether minimum  $V_{REF}$  or maximum  $V_{REF}$ , respectively, occurs at the lower temperature.

Example:

$V_{REF(dev)} = 4.5\text{ mV}$ ,  $V_{REF} = 2500\text{ mV}$  at  $25^\circ\text{C}$ ,

$T_{MAX} - T_{MIN} = 125^\circ\text{C}$  for LM431SAI.

$$|\alpha V_{REF}| = \frac{\left( \frac{4.5\text{ mV}}{2500\text{ mV}} \right) \cdot 10^6}{125^\circ\text{C}} = 14.4\text{ ppm}/^\circ\text{C}$$

Because minimum  $V_{REF}$  occurs at the lower temperature, the coefficient is positive.

# LM431SA, LM431SB, LM431SC

## TEST CIRCUITS

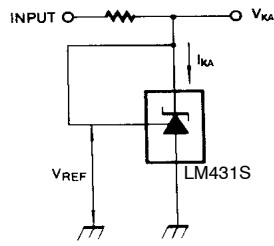


Figure 2. Test Circuit for  $V_{KA} = V_{REF}$

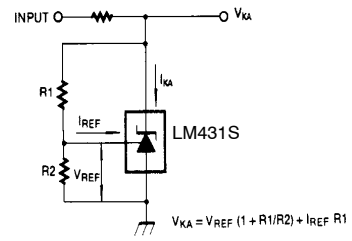


Figure 3. Test Circuit for  $V_{KA} \geq V_{REF}$

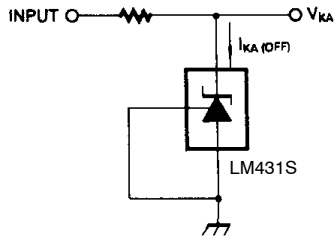


Figure 4. Test Circuit for  $I_{KA(OFF)}$

# LM431SA, LM431SB, LM431SC

## TYPICAL APPLICATIONS

$$V_o = \left(1 + \frac{R_1}{R_2}\right) V_{ref}$$

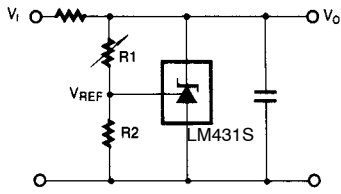


Figure 5. Shunt Regulator

$$V_o = \left(1 + \frac{R_1}{R_2}\right) V_{ref}$$

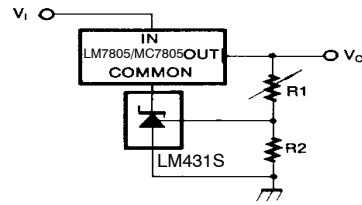


Figure 6. Output Control for Three-Terminal Fixed Regulator

$$V_o = \left(1 + \frac{R_1}{R_2}\right) V_{ref}$$

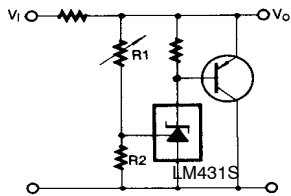


Figure 7. High Current Shunt Regulator

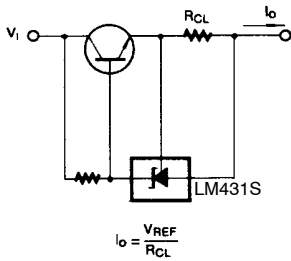


Figure 8. Current Limit or Current Source

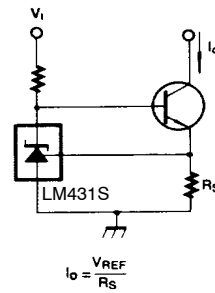


Figure 9. Constant-Current Sink

# LM431SA, LM431SB, LM431SC

## TYPICAL PERFORMANCE CHARACTERISTICS

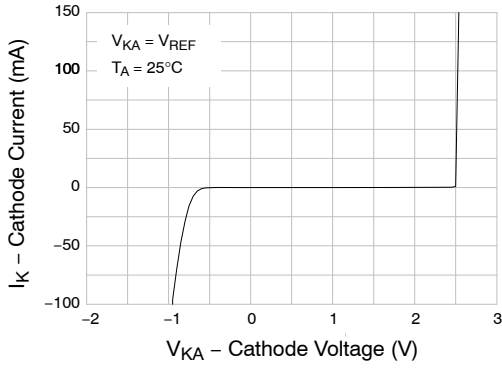


Figure 10. Cathode Current vs. Cathode Voltage

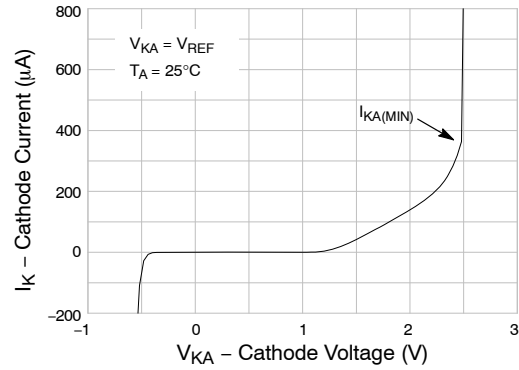


Figure 11. Cathode Current vs. Cathode Voltage

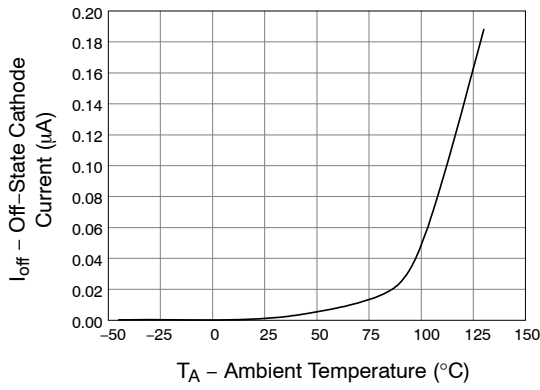


Figure 12. OFF-State Cathode Current vs. Ambient Temperature

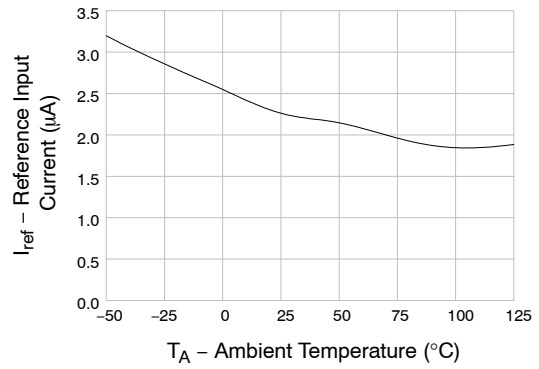


Figure 13. Reference Input Current vs. Ambient Temperature

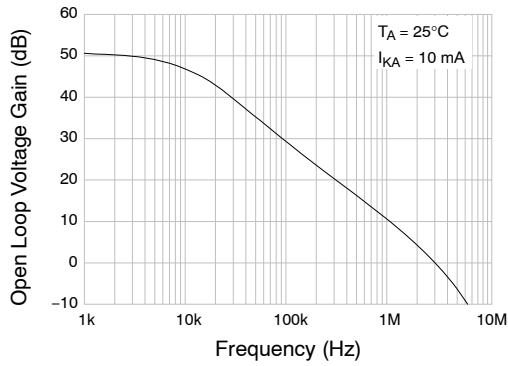


Figure 14. Frequency vs. Small Signal Voltage Amplification

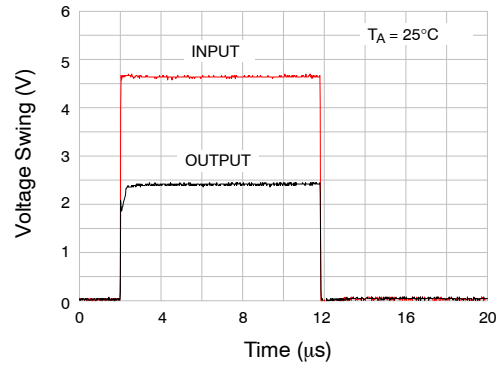


Figure 15. Pulse Response

# LM431SA, LM431SB, LM431SC

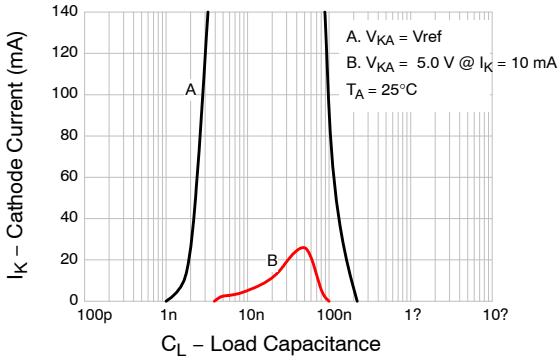


Figure 16. Stability Boundary Conditions

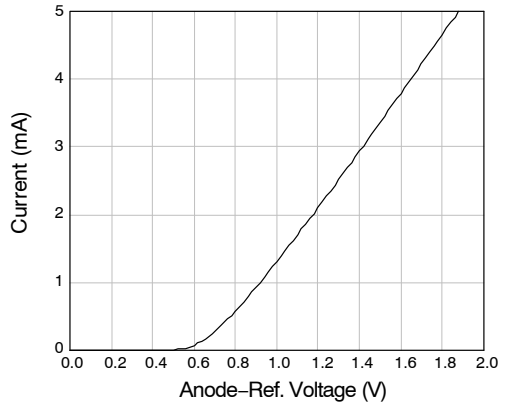


Figure 17. Anode-Reference Diode Curve

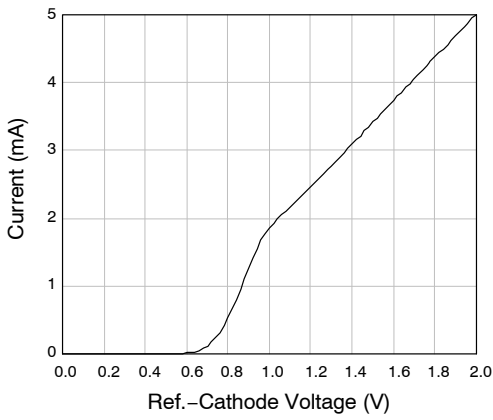


Figure 18. Reference-Cathode Diode Curve

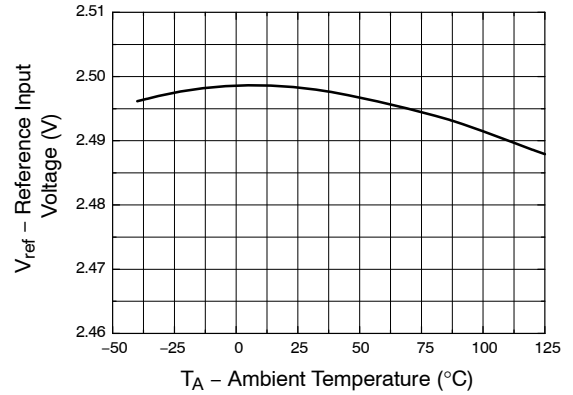


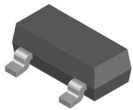
Figure 19. Reference Input Voltage vs. Ambient Temperature



# MECHANICAL CASE OUTLINE

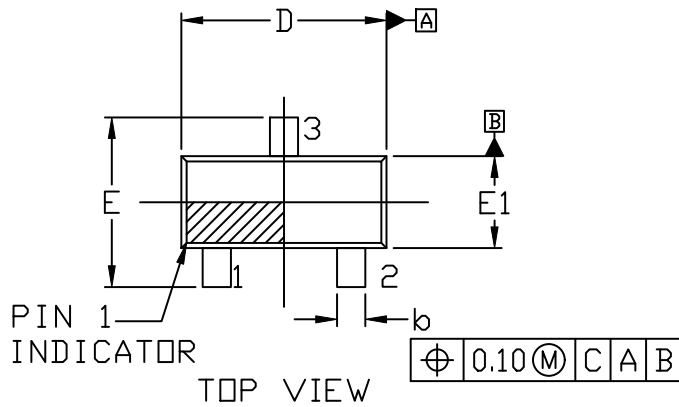
## PACKAGE DIMENSIONS

ON Semiconductor®



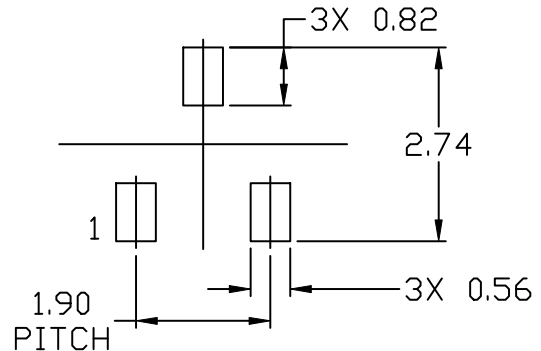
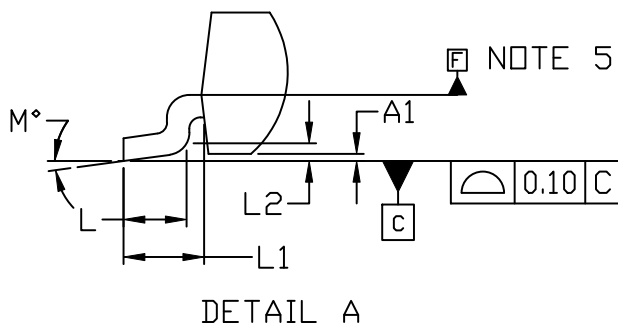
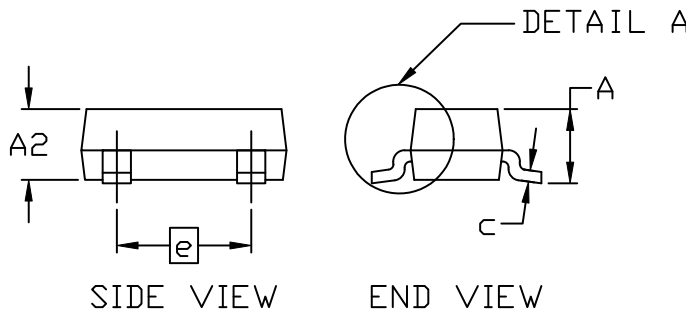
**SOT23-FL3L**  
CASE 318AB  
ISSUE O

DATE 11 DEC 2020



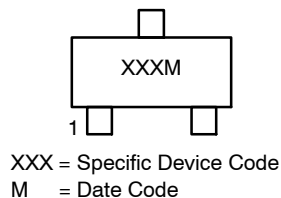
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.127 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
  4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM F.
  5. DATUMS A AND B ARE TO BE DETERMINED AT DATUM F.
  6. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.
  7. LEAD THICKNESS (c) AND LEAD WIDTH (b) INCLUDE PLATING THICKNESS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	---	---	1.15
A1	0.00	---	0.10
A2	0.90	1.00	1.10
b	0.30	---	0.50
c	0.127 REF		
D	2.80	2.90	3.00
E	2.25	2.40	2.55
E1	1.20	1.30	1.40
e	1.90 BSC		
L	0.30	---	---
L1	0.55 REF		
L2	0.25 REF		
M	0°	---	8°



\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM\*



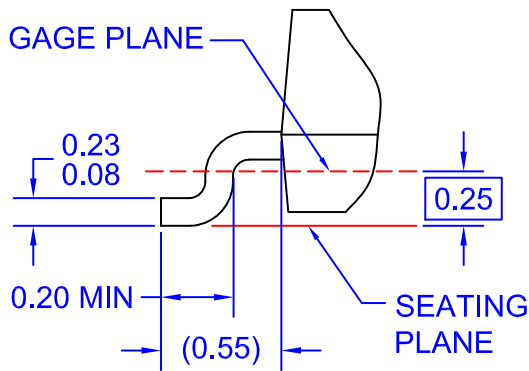
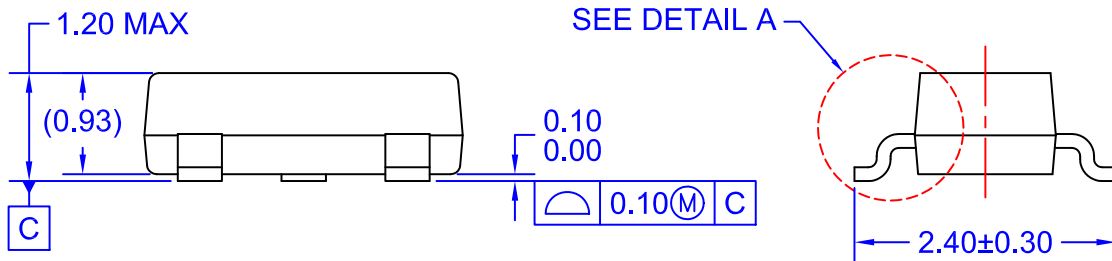
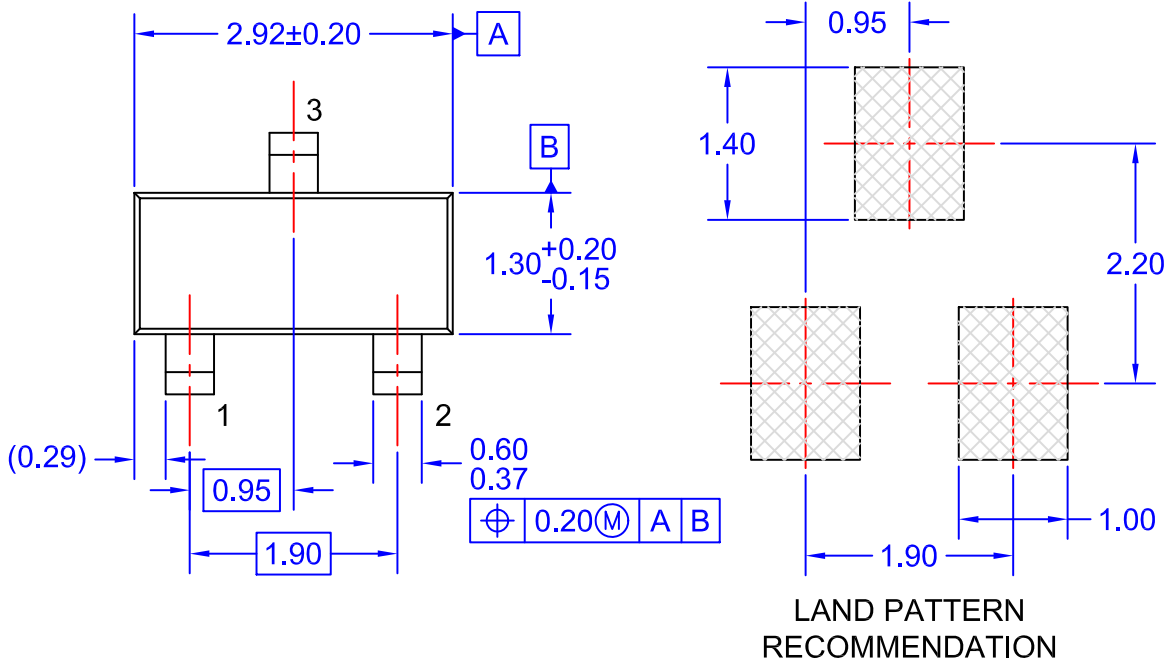
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "μ", may or may not be present. Some products may not follow the Generic Marking.

<b>DOCUMENT NUMBER:</b>	<b>98AON27911H</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>SOT23-FL3L</b>	<b>PAGE 1 OF 1</b>

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**SOT-23**  
**CASE 318BM**  
**ISSUE O**

DATE 31 AUG 2016



**DETAIL A**  
 SCALE: 2X

**NOTES: UNLESS OTHERWISE SPECIFIED**

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.

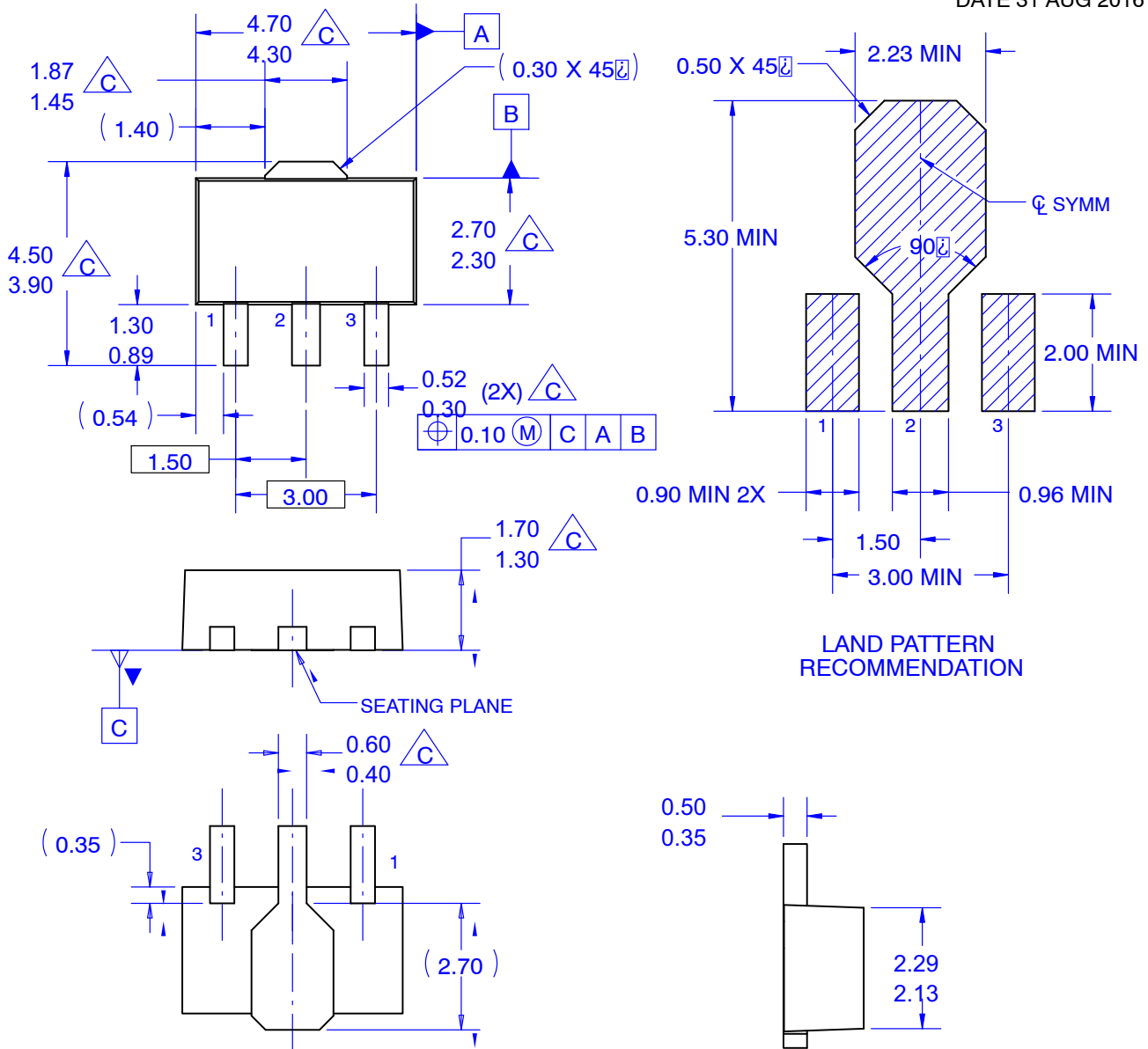
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**SOT-89 3 LEAD**  
**CASE 528AH**  
**ISSUE O**

DATE 31 AUG 2016



**NOTES: UNLESS OTHERWISE SPECIFIED.**

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- B. ALL DIMENSIONS ARE IN MILLIMETERS.
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